Amendment to the Specification

Please replace paragraph [0002] with the following amended paragraph:

[0002] In recent years, organic semiconductors comprised of amorphous film of organic substances are in wide use in a variety of electronic devices. For example, an organic amorphous flim is formed by preparing a coating composition comprised of a binder resin such as polycarbonate resin and a low molecular weight organic compound such as a triphenylamine derivative having photoelectric function dissolved in a suitable organic solvent and then by coating and drying the composition. The film thus formed is used as a positive hole transport layer in electrophotographic devices, as described in JP-A-1999-174707. Similarly, an organic amorphous flim is formed by preparing a coating dissolved in a suitable organic solvent and then by coating and drying the composition. The flim in solar batteries, as described in JP-A-2000-174657 JP-A-2001-007355.